

# **TAN150**

# 150 Watts, 50 Volts, Pulsed **Avionics 960 - 1215 MHz**

### **GENERAL DESCRIPTION**

The TAN150 is a high powered COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 960-1215 MHz. The device has gold thin-film metallization and diffused ballasting for proven highest MTTF. The transistor includes input and output prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.

# **CASE OUTLINE** 55AT, Style 1

#### **ABSOLUTE MAXIMUM RATINGS**

#### **Maximum Power Dissipation**

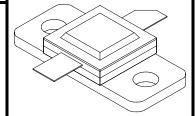
Device Dissipation @25°C 583 W

#### **Maximum Voltage and Current**

Collector to Base Voltage (BV<sub>ces</sub>) 55 V Emitter to Base Voltage (BV<sub>ebo</sub>) 3.5 V Collector Current (I<sub>c</sub>) 15.0 A

#### **Maximum Temperatures**

-65 to +150 °C Storage Temperature Operating Junction Temperature +200 °C



## **ELECTRICAL CHARACTERISTICS @ 25°C**

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
P <sub>out</sub>	Power Out	F = 960-1215 MHz	150			W
P <sub>in</sub>	Power Input	Vcc = 50 Volts			30	W
$P_{g}$	Power Gain	PW = 20 μsec	7.0			dB
$\eta_c$	Collector Efficiency	DF = 5%		38		%
VSWR	Load Mismatch Tolerance	F = 1090 MHz			10:1	

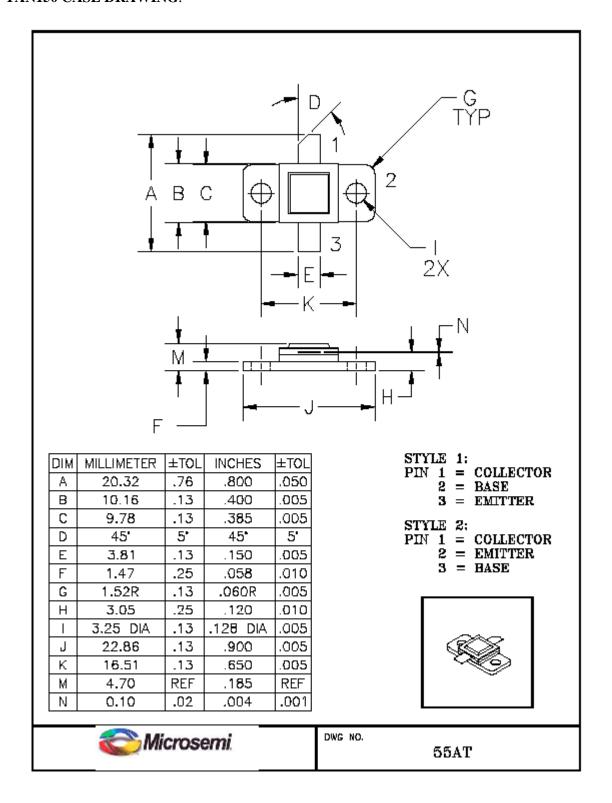
#### FUNCTIONAL CHARACTERISTICS @ 25°C

$\mathrm{BV}_{\mathrm{ebo}}$	Emitter to Base Breakdown	Ie = 10  mA	3.5		V
$BV_{ces}$	Collector to Emitter Breakdown	Ic = 50  mA	55		V
$h_{\mathrm{FE}}$	DC – Current Gain	Vce = 5V, $Ic = 1 A$	10		
θjc <sup>1</sup>	Thermal Resistance			0.3	°C/W

NOTE 1: At rated output power and pulse conditions

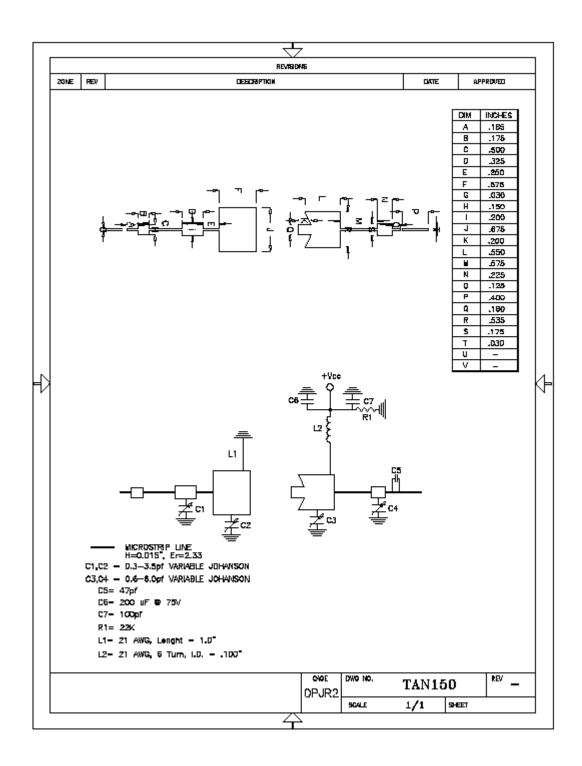
Rev A: Updated June 2009

#### **TAN150 CASE DRAWING:**



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### **TAN150 TEST CIRCUIT:**



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